ORDERING INFORMATION

Device	Temperature Range	Package
MC1420G	0°C to +70°C	Metal Can
MC1520F	−55°C to +125°C	Ceramic Flat
MC1520G	−55°C to +125°C	Metal Can

MC1420
MC1520

3

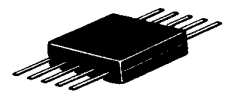
DIFFERENTIAL OUTPUT OPERATIONAL AMPLIFIER

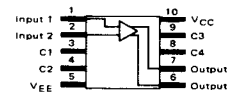
A wide-band, general-purpose operational amplifier which features both differential inputs and outputs. Open loop gain is approximately 3000 V/V but may be adjusted with external feedback components. This device is particularly useful in applications which require differential outputs.

- Differential Input and Differential Output
- Wide Closed-Loop Bandwidth; 10 MHz
- Differential Gain; 70 dB
- High Input Impedance; 2.0 Megohms:
- Low Output Impedance; 50 ohms

OPERATIONAL AMPLIFIER

SILICON MONOLITHIC
INTEGRATED CIRCUIT



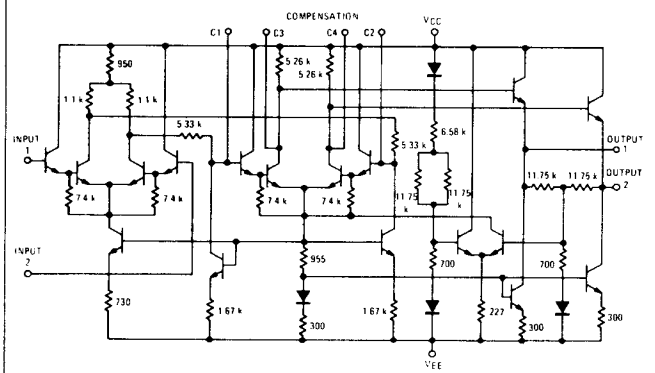


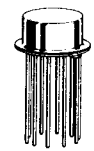
F SUFFIX
CERAMIC PACKAGE
CASE 606
(TO-91)

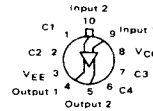
MAXIMUM RATINGS (T_A = +25°C unless otherwise noted)

Rating		Symbol	Value	Unit
Power Supply Voltage		V_{CC} V_{EE}	+8.0 -8.0	Vdc
Differential Input Signal		V_{in}	±8.0	Vdc
Load Current		I_{L1}, I_{L2}	15	mA
Power Dissipation (Package Limitation) Metal Package Derate above T_A = +25°C Flat Package Derate above T_A = +25°C		P_D	 680 4.6 500 3.3	 mW mW/°C mW mW/°C
Operating Temperature Range	MC1520 MC1420	T_A	-55 to +125 0 to + 75	°C
Storage Temperature Range		T_{stg}	-65 to +150	°C

FIGURE 1 – CIRCUIT SCHEMATIC







(TOP VIEW)
G SUFFIX
METAL PACKAGE
CASE 603

SINGLE-ENDED ELECTRICAL CHARACTERISTICS

(V_{CC} = +6.0 Vdc, V_{EE} = -6.0 Vdc, T_A = +25°C unless otherwise noted.)

Characteristic	Symbol	MC1520 Min	MC1520 Typ	MC1520 Max	MC1420 Min	MC1420 Typ	MC1420 Max	Unit
Open Loop Voltage Gain (T_{low} ② ≦ T_A ≦ T_{high} ②)	A_{vol}	1000 60	1500 64	–	750 –	1500 64	–	V/V dB
Output Impedance (f = 20 Hz)	z_{os}	–	50	100	–	50	–	ohms
Input Impedance (f = 20 Hz)	z_{is}	0.5	2.0	–	–	2.0	–	megohms
Output Voltage Swing (R_L = 7.0 kΩ [Figure 8])	V_O	±3.5	±4.0	–	±3.0	±4.0	–	V_{peak}
Input Common-Mode Voltage Swing	V_{ICR}	±2.0	±3.0	–	–	±3.0	–	V_{peak}
Common-Mode Rejection Ratio	CMRR	75	90	–	60	90	–	dB
Input Bias Current ($I_{IB} = \frac{I_1 + I_2}{2}$, T_A = +25°C)	I_{IB}	–	0.8	2.0	–	2.0	4.0	μA
Input Offset Current ($I_{IO} = I_1 - I_2$) ($I_{IO} = (1 - I_2$, $T_A = T_{low}$) ($I_{IO} = I_1 - I_2$, $T_A = T_{high}$)	$\|I_{IO}\|$	– – –	30 – –	100 200 200	– – –	30 – –	200 – –	nA
Input Offset Voltage (T_A = +25°C)	$\|V_{IO}\|$	–	5.0	10	–	5.0	15	mV
Step Response								
Gain = 1.0, 10% Overshoot R_1 = 10 kΩ R_2 = 10 kΩ R_3 = 5.0 kΩ C_s = 39 pF	t_{THL} t_{PLH},t_{PHL} dV_{out}/dt ①	– – –	80 70 5.0	– – –	– – –	80 70 5.0	– – –	ns ns V/μs
Gain = 10, 10% Overshoot R_1 = 10 kΩ R_2 = 100 kΩ R_3 = 10 kΩ C_s = 10 pF	t_{THL} t_{PLH},t_{PHL} dV_{out}/dt ①	– – –	80 70 15	– – –	– – –	80 70 15	– – –	ns ns V/μs
Gain = 100, No Overshoot R_1 = 1.0 kΩ R_2 = 100 kΩ R_3 = 1.0 kΩ C_s = 1.0 pF	t_{THL} t_{PLH},t_{PHL} dV_{out}/dt ①	– – –	80 70 30	– – –	– – –	80 70 30	– – –	ns ns V/μs
Open Loop, No Overshoot R_1 = 50 Ω R_2 = ∞ R_3 = 50 Ω C_s = 0	t_{THL} t_{PLH},t_{PHL} dV_{out}/dt ①	– – –	180 70 35	– – –	– – –	180 70 35	– – –	ns ns V/μs
Bandwidth: (Open Loop [Figure 4]) (Closed Loop [Unity Gain]) (Figure 5)	–	– –	2.0 10	– –	– –	2.0 10	– –	MHz
Input Noise Voltage (Open Loop) (5.0 Hz - 5.0 MHz)	$V_{n(in)}$	–	11	15	–	11	–	μV(rms)
Average Temperature Coefficient of Input Offset Voltage (R_S = 50 Ω, $T_A = T_{low}$ to T_{high})	$\Delta V_{IO}/\Delta T$	–	2.0	–	–	2.0	–	μV/°C
DC Power Dissipation (V_O = 0)	P_D	–	120	240	–	120	240	mW
Power Supply Sensitivity (V_O = 0)	$S^{\pm}$	–	250	450	–	250	–	μV/V

① dV_{out}/dt = Slew Rate

② T_{low} = 0°C for MC1420, -55°C for MC1520 T_{high} = +75°C for MC1420 +125°C for MC1520

DIFFERENTIAL ELECTRICAL CHARACTERISTICS

(V_{CC} = +6.0 Vdc, V_{EE} = -6.0 Vdc, T_A = +25°C, unless otherwise noted.)

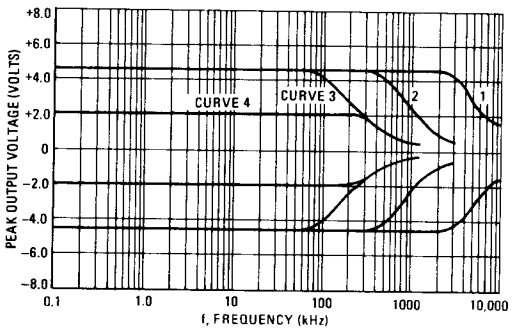
Characteristic	Symbol	MC1520 Min	MC1520 Typ	MC1520 Max	MC1420 Min	MC1420 Typ	MC1420 Max	Unit
Gain (Open Loop)	A_{vol}	2000 66	3000 70	–	1500 64	3000 70	–	V/V dB
Input Impedance (f = 20 Hz)	z_{id}	0.5	2.0	–	–	2.0	–	megohms
Output Impedance (f = 20 Hz)	z_{od}	–	100	200	–	100	–	ohms
Common-Mode Output Voltage	$V_{O(CM)}$	-0.5	0	+0.5	–	0	–	Vdc
Output Voltage Swing (R_L = 7.0 kΩ)	V_O	±7.0	±8.0	–	±6.0	±8.0	–	V_{peak}

3

TYPICAL CHARACTERISTICS

(V_{CC} = +6.0 Vdc, V_{EE} = -6.0 Vdc, T_A = +25°C unless otherwise noted.)

FIGURE 2 – LARGE SIGNAL SWING versus FREQUENCY



TEST CIRCUIT

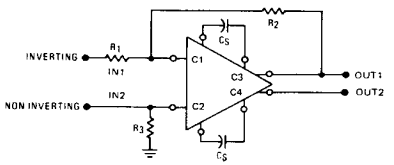


FIGURE NO.	CURVE NO.	MODE	VOLTAGE GAIN	TEST CONDITIONS R_1 (Ω)	R_2 (Ω)	R_3 (Ω)	C_S (pF)	NOISE OUTPUT mV (rms)
2	1	INVERTING	100	1.0 k	100 k	1.0 k	1.0	2.0
	2	INVERTING	10	10 k	100 k	10 k	10	0.55
	3	INVERTING	1.0	10 k	10 k	5.0 k	39	0.17
	4	NON-INVERTING	1.0	∞	10 k	10 k	39	0.17
3	1	NON-INVERTING	A_{vol}	0	∞	50	1.0	1.0
	2	NON-INVERTING	A_{vol}	0	∞	50	10	2.0
	3	NON-INVERTING	A_{vol}	0	∞	50	39	5.2
4	1	NON-INVERTING	100	100	10 k	100	1.0	2.0
	2	NON-INVERTING	10	1.0 k	9.1 k	910	10	0.55
	3	NON-INVERTING	1.0	∞	10 k	10 k	39	0.17

FIGURE 3 – OPEN LOOP VOLTAGE GAIN

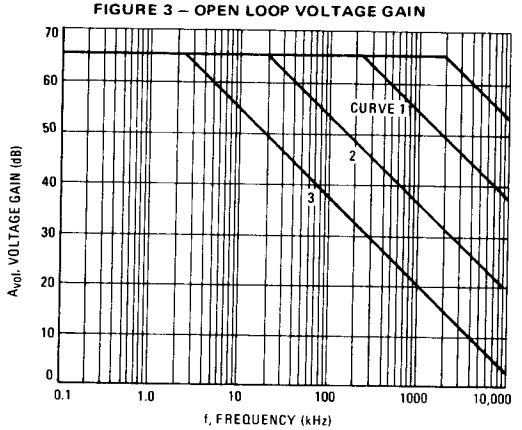
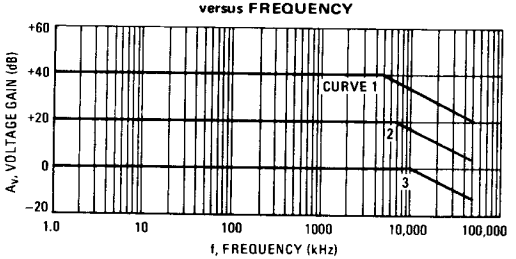


FIGURE 4 – CLOSED LOOP VOLTAGE GAIN versus FREQUENCY



TYPICAL OUTPUT CHARACTERISTICS

(V_{CC} = +6.0 Vdc, V_{EE} = -6.0 Vdc, T_A = +25°C unless otherwise noted.)

FIGURE 5 – POWER DISSIPATION versus POWER SUPPLY VOLTAGE

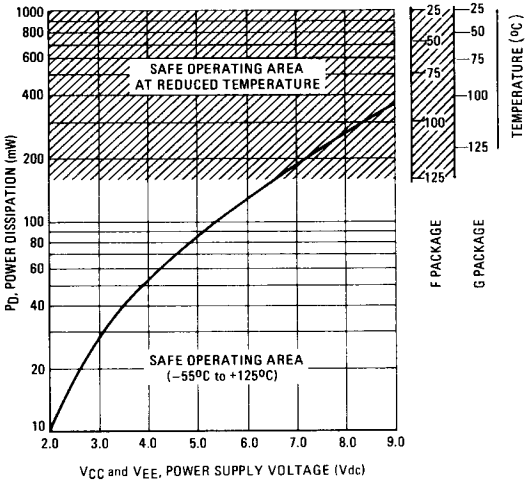


FIGURE 6 – OPEN LOOP VOLTAGE GAIN versus SUPPLY VOLTAGE

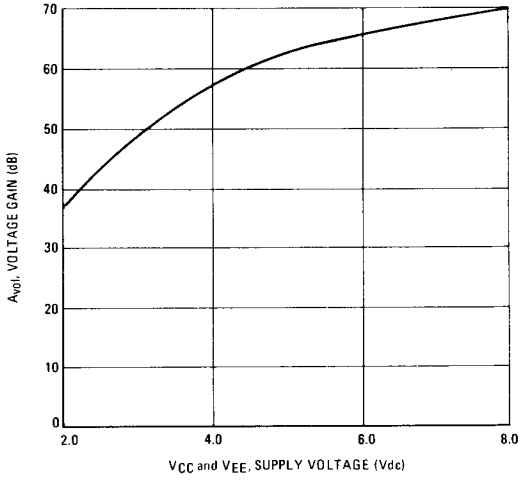


FIGURE 7 – SINGLE ENDED OUTPUT VOLTAGE versus LOAD RESISTANCE

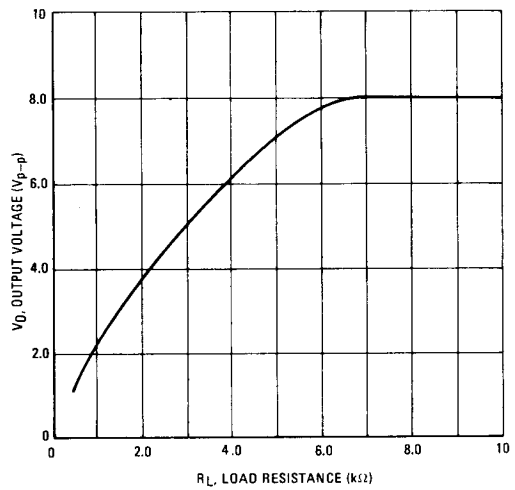


FIGURE 8 – OUTPUT NOISE VOLTAGE versus SOURCE RESISTANCE